

Current Transducer LAH 25-NP

For the electronic measurement of currents: DC, AC, pulsed..., with galvanic separation between the primary circuit and the secondary circuit.



$I_{PN} = 8-12-25 A$



Electrical data

Current consumption

 $I_{\rm C}$

I_{PN} I_{PM}	Primary nominal RMS current, measurin		25 0	±55		A A
R_{M}	Measuring resistance @ 2)		$T_{A} = 7$	O °C	$T_A = 8$	5°C
			$R_{ m M min}$	R _{M max}	$R_{\rm M min}$	$R_{ m Mmax}$
	with ±12 V	@ I_{PN} [±At DC]	0	284	0	280 Ω
		@ I_{PN} [At RMS] 3)	0	182	0	178 Ω
	with ±15 V	@ I_{PN} [±At DC]	67	398	70	394 Ω
		@ I _{PN} [At RMS] 3)	67	263	70	259 Ω
		Q $I_{P} < I_{PN}^{4}$				
$I_{\rm SN}$	Secondary nominal RMS		25			mA
$N_{\rm p}/N$	_s Turns ratio		1-2-	3:100	0	
$\dot{U_{\rm c}}$	Supply voltage (±5 %)		±12	15		V

Accuracy - Dynamic performance data

$\varepsilon_{\mathrm{tot}}$	Total error ⁵⁾ @ I_{PN} , T_A = 25 °C	±0.3		%
ε_{L}	Linearity error	< 0.2		%
		Тур	Max	
I_{o}	Offset current referred to primary @ I_P = 0, T_A = 25 °C		±150	mA
I_{o}	Offset current referred to secondary @ I_p = 0, T_A = 25 °C		±0.15	mA
I_{OM}	Magnetic offset current @ I_P = 0, referred to secondary			
	and specified $R_{\rm M}$, after an overload of 5 × $I_{\rm PN}$	±0.20	±0.25	mA
I_{OT}	Temperature variation of $I_{\rm O}$, referred to secondary			
	0 °C +70 °C	±0.10	±0.60	mA
	−25 °C +85 °C	±0.10	±0.70	mA
t _{D 10}	Delay time to 10 % of the final output value for $I_{\rm PN}$ step $^{6)}$	< 200		ns
t _{D 90}	Delay time to 90 % of the final output value for I_{PN} step ⁶⁾	< 500		ns
BW	Frequency bandwidth (-1 dB)	DC	200	kHz

General data

T_{Δ}	Ambient operating temperature		–25 +85	°C
T_{Ast}	Ambient storage temperature		-40 + 90	°C
$R_{\rm S}$	Resistance of secondary winding	@ $T_A = 70 ^{\circ}\text{C}$	72	Ω
Ü		@ $T_{A} = 85 ^{\circ}\text{C}$	76	Ω
m	Mass		20	g
	Standards		EN 50178: 1997	

Notes: 1) During 10 s, with $R_{\rm M} \le 109 \ \Omega \ (U_{\rm C} = \pm 15 \ {\rm V})$

- ²⁾ Calculation of $R_{\rm M\,min}$ with the maximum power of the transistors = 0.307 W @ 70 °C and the maximum power of the transistors = 0.302 W @ 85 °C
- 3) Sinusoidal wave 50 Hz
- $^{\rm 4)}$ The minimum measuring resistance $R_{\rm M}$ may be lower (see "LAH technical information" leaflet)
- $^{\rm 5)}$ Without $I_{\rm O}\,\&\,I_{\rm O\,M}$
- ⁶⁾ For a $di/dt = 100 \text{ A/}\mu\text{s}$.

Features

- Closed loop (compensated) multirange current transducer using the Hall effect
- Printed circuit board mounting
- Insulating plastic case recognized according to UL 94-V0.

Advantages

- Excellent accuracy
- Very good linearity
- Low temperature drift
- Optimized delay time
- No insertion losses
- High immunity to external interference
- Current overload capability.

Applications

- AC variable speed drives and servo motor drives
- Static converters for DC motor drives
- · Battery supplied applications
- Uninterruptible Power Supplies (UPS)
- Switched Mode Power Supplies (SMPS)
- Power supplies for welding applications.

Application domain

Industrial.

10 (@ ±15 V) +I_s

mΑ



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In	Insulation coordination					
U_{d}	RMS voltage for AC insulation test, 50 Hz, 1 min	5	kV			
U_{Ni}	Impulse withstand voltage 1.2/50 μs	12	kV			
$U_{\rm e}$	Partial discharge extinction RMS voltage @10 pC	> 2 Min	kV			
$d_{\rm Cp}$	Creepage distance 1)	12	mm			
d_{CI}	Clearance 1)	12	mm			
CTI	Comparative tracking index (group IIIa)	175				

Note: 1) On PCB with soldering pattern UTEC93-703.

Applications examples

According to EN 50178 and IEC 61010-1 standards and following conditions:

- Over voltage category OV 3
- Pollution degree PD2
- Non-uniform field

	EN 50178	IEC 61010-1		
$\overline{d_{\mathrm{Cp}},d_{\mathrm{Cl}},U_{\mathrm{Ni}}}$	Rated insulation voltage	Nominal voltage		
Basic insulation	1000 V	1000 V		
Reinforced insulation	500 V	500 V		

Safety

This transducer must be used in limited-energy secondary circuits according to IEC 61010-1.

This transducer must be used in electric/electronic equipment with respect to applicable standards and safety requirements in accordance with the manufacturer's operating instructions.



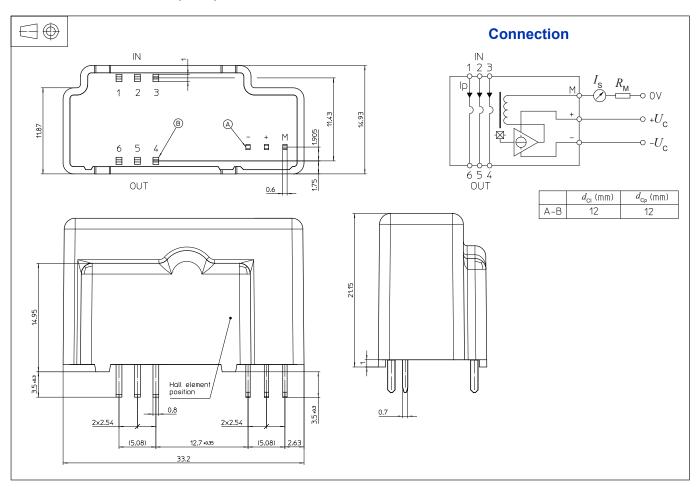
Caution, risk of electrical shock

When operating the transducer, certain parts of the module can carry hazardous voltage (e.g. primary busbar, power supply). Ignoring this warning can lead to injury and/or cause serious damage.

This transducer is a build-in device, whose conducting parts must be inaccessible after installation. A protective housing or additional shield could be used. Main supply must be able to be disconnected.



Dimensions LAH 25-NP (in mm)



Number of primary turns	Primary current nominal $I_{\scriptscriptstyle{\mathrm{PN}}}$ [A]	Primary current maximum $I_{\scriptscriptstyle m P}$ [A]	Nominal output current I_{SN} [mA]	Turns ratio $N_{\scriptscriptstyle m P}/N_{\scriptscriptstyle m S}$	Primary resistance $R_{_{ m P}}$ [m Ω]	Primary insertion inductance $L_{_{ m P}}$ [μ H]	Recommended PCB connections
1	25	55	25	1 : 1000	0.18	0.012	3 2 1 IN 000 000 OUT 4 5 6
2	12	27	24	2:1000	0.81	0.054	3 2 1 IN 0 0 0 0 0 0 0 0 0
3	8	18	24	3 : 1000	1.62	0.110	3 2 1 IN 0 0 0 0 0 OUT 4 5 6

Mechanical characteristics

- General tolerance
- Fastening & connection of primary Recommended PCB hole
- Fastening & connection of secondary Recommended PCB hole

±0.2 mm 6 pins 1 mm × 0.8 mm 1.5 mm

3 pins 0.7 mm × 0.6 mm

1.2 mm

Remarks

- I_s is positive when I_p flows from terminals 1, 2, 3 (IN) to terminals 6, 5, 4 (OUT).
- The jumper temperature and PCB should not exceed 100 °C.
- This is a standard model. For different versions (supply voltages, turns ratio, unidirectional measurements...), please contact us.